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BRS	BRS	BRS	BRS	BRS	BRS	BRS	Туре
L7 ·	L6	L5	L4	L3	L2	Ľ,	#
178	0	74	479	60	51	720	Hits
lateral\$4 adj double adj diffus\$5 adj (MOS\$3 or MOSFET\$1)	lateral\$4 adj diffus\$5 adj double adj metal adj oxide adj semiconduct\$4	(lateral\$4 adj double adj diffus\$5 adj metal adj oxide adj semiconduct\$4) or (lateral\$4 adj double-diffus\$5 adj metal adj oxide adj semiconduct\$4)	DS\$3) or LDD-MOS\$2 or LDD-MOS	lateral\$4 adj diffus\$5 adj (MOS\$3 or MOSFET\$1)	lateral\$4 adj diffus\$5 adj metal adj oxide adj semiconduct\$4	LDMOS\$2 or LD-MOS\$2 or (LD adj MOS\$3) or LDMOSFET\$1 or (LD adj MOSFET\$1)	Search Text
USPAT; US-PGPUB; EFO; JPO; DERWENT; IBM TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	USPAT; or US-PGPUB; EPO; JPO; DERWENT; IBM TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	DBs
2002/03/14	2002/03/14	2002/03/14	2002/03/14	2002/03/14	2002/03/14	2002/03/14	Time Stamp
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0	0	0	0	0	0	0	Err

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"LDD" or ((light\$3 or USPAT;) adj (source\$1 or USPAT; or (lightly-doped US-PGPUB; 2002/03/14 ce\$1 or drain\$1)) EPO; JPO; 11:45 low or	ALDD" or ((light\$3 adj (source\$1 or USPAT; or (lightly-doped US-PGPUB; e\$1 or drain\$1)) EPO; JPO; ow or 1) near4 IBM TDB or drain\$1))	LDD" or ((lights; adj (source\$1 o; or (lightly-dope; e\$1 or drain\$1)) ow or 1) near4 or drain\$1))	LDD\$1 or "LDD" adj dop\$3) adj drain\$1)) or (adj (source\$1 or ((shallow o extension\$1) n	18145	L13	BRS	
2 or LD-NMOS\$2 or USPAT; NMOS\$3) or US-PGPUB; ET\$1 or LD-NMOSFET\$1 EPO; JPO; adj NMOSFET\$1) IBM TDB	MOS\$2 or or LD-NMOSFET\$1	LD-NMOS\$2 or S\$3) or or LD-NMOSFET\$ NMOSFET\$1)	LDNMOS\$2 or LD-N (LD adj.NMOS\$3) LDNMOSFET\$1 or I or (LD adj NMOSI	U	L12	BRS	12
LD-PMOS\$2 or USPAT; S\$3) or US-PGPUB; 2002/03/14 or LD-PMOSFET\$1 EPO; JPO; 11:42 PMOSFET\$1) IBM TDB	-PMOS\$2 or) or LD-PMOSFET\$1 SFET\$1)	. O. O. I.	LDPMOS\$2 or LD- (LD adj PMOS\$3) LDPMOSFET\$1 or or (LD adj PMOS	10	L11	BRS	11
near7 (MOS or USPAT; pr NMOS or US-PGPUB; 2002/03/14 or PMOS or EPO; JPO; 13:12 IBM TDB	MOS or or or	MOS o	lateral\$4 near7 MOSFET\$1 or NMO: NMOSFET\$1 or PMO: PMOSFET\$1)	2322	L10	BRS	10
near7 (metal adj US-PGPUB; 2002/03/14 semiconduct\$4) EPO; JPO; 11:40 IBM TDB	(metal adj onduct\$4)	(metal onduct\$4	lateral\$4 near7 oxide adj semic	249	L9	BRS	Q
USPAT; dj diffus\$5 adj US-PGPUB; 2002/03/14 (MOS\$3 or EPO; JPO; 11:39 DERWENT; 11:39	USPA fus\$5 adj US-P or EPO; DERW IBM	fus\$5 or	lateral\$4 adj double adj (M0 MOSFET\$1)	0	18	BRS	∞
Text DBs Time Stamp ents tion	Text		Search	Hits	T #	Туре	

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		2002/03/14.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	1 or 2 or 3 or 4 or 5 or 6 or 7 or 8 or 9 or 10 or 11 or 12 or 19	3486	L20	BRS	20
		2002/03/14	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	lateral\$4 near7 (DMOS or DMOSFET\$1)	4 55	L19	BRS	19
		2002/03/14	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	(1 or 2 or 3) and 13 and 15	73	L18	BRS	18
		2002/03/14	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	16 and 13 and 14 and 15	533	L17	BRS	17
		2002/03/14	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	1 or 2 or 3 or 4 or 5 or 6 or 7 or 8 or 9 or 10 or 11 or 12	331.5	L16	BRS	16
		2002/03/14	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	(field adj (oxide\$1 or isolat\$5)) or LOCOS\$2 or trench\$2 or STI\$1 or (shallow adj trench\$2 adj isolat\$5)	140917	L15	BRS	15
		2002/03/14	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	(gate\$1 or electrode\$1) and source\$1 and drain\$1	152308	L14	BRS	14
Error Defin ition	Comm De	Time Stamp	DBs	Search Text	Hits	۲ #	Туре	

	Type	# 1	Hits	Search Text	DBs	Time Stamp	Comm	Defin ition	Err
	,				USPAT; US-PGPUB;	2002/03/14		,	
21	BRS	L21	547	20 and 13 and 14 and 15	EPO; JPO; DERWENT; IBM TDB	13:16	v		
22	IS&R	L22	387	("438/286").CCLS.	USPAT; US-PGPUB	2002/03/14 16:16			0
					USPAT; US-PGPUB;	2002/03/14			0
23	BRS	L23	40	21 and 22	DERWENT; IBM TDB	16:17			
24	IS&R	L24	Р	("6255154").PN.	USPAT; US-PGPUB	2002/03/14 18:21			0
25	BRS	L25	0	6255154.URPN.	USPAT; US-PGPUB	2002/03/14			0
. 6	IS&R	L26	V	(("5382536") or ("5517046") or ("5541435") or ("5578514") or ("5844272") or ("5854566") or ("5869371") or ("6033948") or ("6051482")).PN.	USPAT; US-PGPUB	2002/03/14			0
27	IS&R	L27	1	("5541123").PN.	USPAT;	2002/03/14	·		0